1 GHz wideband low-noise amplifier with bypassRev. 2 — 26 May 2014Pro

Product data sheet

#### **Product profile** 1.

## **1.1 General description**

The BGU7045 MMIC is a 3.3 V wideband amplifier with bypass mode. It is designed specifically for high linearity, low-noise applications over a frequency range of 40 MHz to 1 GHz. It is especially suited for Set-Top Box applications.

The LNA is housed in a 6-pin SOT363 plastic SMD package.

### 1.2 Features and benefits

- Voltage supply of 3.3 V
- Internally biased
- Programmable between G<sub>p</sub> = 14 dB and bypass
- Flat gain between 40 MHz and 1 GHz
- Noise figure of 2.8 dB
- High linearity with an IP3<sub>O</sub> of 29 dBm
- 75 Ω input and output impedance
- Power-down during bypass mode
- Bypass mode current consumption < 5 mA</p>
- ESD protection > 2 kV Human Body Model (HBM) and >1.5 kV Charged Device Model (CDM) on all pins

## 1.3 Applications

- Terrestrial and cable Set-Top Boxes (STB)
- Silicon and "Can" tuners
- Personal Video Recorders (PVR) and Digital Video Recorders (DVR)
- Home networking and in-house signal distribution



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## 1.4 Quick reference data

#### Table 1. Quick reference data

 $T_{amb}$  = 25 °C; typical values at  $V_{CC}$  = 3.3 V;  $Z_S$  =  $Z_L$  = 75  $\Omega$ ;  $R_{bias}$  = 18  $\Omega$ ; 40 MHz  $\leq$   $f_1 \leq$  1000 MHz.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>CC</sub>	supply voltage	RF input AC coupled	3.1	3.3	3.5	V
I <sub>CC(tot)</sub>	total supply current	G <sub>p</sub> = 14 dB mode [1]	30	34	38	mA
		bypass mode [1]	-	3	-	mA
T <sub>amb</sub>	ambient temperature		-40	-	+85	°C
NF	noise figure	G <sub>p</sub> = 14 dB mode [1]	-	2.8	-	dB
		bypass mode [1]	-	2.5	-	dB
P <sub>L(1dB)</sub>	output power at 1 dB gain compression	G <sub>p</sub> = 14 dB mode; [1] 1 GHz	-	13	-	dBm
IP3 <sub>0</sub>	output third-order intercept point	G <sub>p</sub> = 14 dB mode [1][2]	-	29	-	dBm

[1] Mode depends on setting of  $V_{CTRL}$ ; see <u>Table 8</u>.

[2] The fundamental frequency (f<sub>1</sub>) is 1000 MHz. The intermodulation product (IM3) is  $2 \times f_2 - f_1$ , where  $f_2 = f_1 \pm 1$  MHz. Input power  $P_i = -10$  dBm.

# 2. Pinning information

Pin	Description	Simplified outline	Graphic symbol
1	RF_OUT		
2	V <sub>CC</sub>		$\mathbf{N}^{3}$
3	n.c.		
4	CTRL		
5	GND		5 4 sym141
6	RF_IN		<i></i>

# 3. Ordering information

#### Table 3. Ordering information

Type number	Package				
	Name	Description	Version		
BGU7045	-	plastic surface-mounted package; 6 leads	SOT363		

## 4. Marking

#### Table 4. Marking codes

Type number	Marking code	Description
BGU7045	LK*	* = p : made in Hong Kong
		* = W : made in China
		* = t : made in Malaysia

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## 5. Limiting values

Table 5.

**Limiting values** 

In accordance with the Absolute Maximum Rating System (IEC 60134).					
Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CC</sub>	supply voltage	RF input AC coupled	-0.6	3.5	V
V <sub>CTRL</sub>	voltage on CTRL pin	[1]	0	V <sub>CC</sub>	V
I <sub>CC(tot)</sub>	total supply current		-	60	mA
P <sub>tot</sub>	total power dissipation	$T_{sp} \leq 100 \ ^{\circ}C$ [2]	-	250	mW
Pi	input power	single tone	-	20	dBm
T <sub>stg</sub>	storage temperature		-65	+150	°C
Tj	junction temperature		-	150	°C
T <sub>amb</sub>	ambient temperature		-40	+85	°C
V <sub>ESD</sub>	electrostatic discharge voltage	Human Body Model (HBM); according to JEDEC standard 22-A114E	2	-	kV
		Charged Device Model (CDM); according to JEDEC standard 22-C101B	1.5	-	kV

[1]  $V_{CTRL}$  must not exceed  $V_{CC}$ ;  $I_{CTRL}$  must be limited to 5 mA (maximum).

 $\label{eq:tau} \begin{tausal}[2] $T_{sp}$ is the temperature at the solder point of the ground lead. \end{tausal}$ 

**Remark:**  $V_{CTRL}$  must not exceed  $V_{CC}$ ;  $I_{CTRL}$  must be limited to a maximum of 5 mA.

## 6. Thermal characteristics

Table 6.	Thermal characteristics			
Symbol	Parameter	Conditions	Тур	Unit
R <sub>th(j-sp)</sub>	thermal resistance from junction to solder point	[1]	130	K/W

[1] Determined by final element method simulation with device mounted on application board and in still air.

# 7. Characteristics

#### Table 7. Characteristics

Symbol Parameter Conditions Min Typ Max Unit				
$I_{amb} = 25 \ ^{\circ}C$ ; typical values at $V_{CC} = 3.3 \ V$ ; $Z_S = Z_L = 75 \ \Omega$ ; $R_{bias} = 18 \ \Omega$ ; 40 MHz $\leq t_1 \leq 1000 \ MHz$ .				

Symbol	Parameter	Conditions		win	тур	wax	Unit
V <sub>CC</sub>	supply voltage	RF input AC coupled		3.1	3.3	3.5	V
I <sub>CC(tot)</sub>	total supply current	G <sub>p</sub> = 14 dB mode	[1]	30	34	38	mA
		bypass mode	[1]	-	3	-	mA
$ s_{21} ^2$	insertion power gain	G <sub>p</sub> = 14 dB mode	[1]	-	14	-	dB
		bypass mode	[1]	-	-2	-	dB
SL <sub>sl</sub>	slope straight line	G <sub>p</sub> = 14 dB mode		-	-1	-	dB
FL	flatness of frequency response	G <sub>p</sub> = 14 dB mode		-	0.2	-	dB
NF	noise figure	G <sub>p</sub> = 14 dB mode	[1]	-	2.8	-	dB
		bypass mode	[1]	-	2.5	-	dB

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Table 7.	<b>Characteristics</b>	continued
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Symbol	Parameter	Conditions		Min	Тур	Max	Unit
RL <sub>in</sub>	input return loss	G <sub>p</sub> = 14 dB mode	[1]	-	20	-	dB
		bypass mode	[1]	-	9	-	dB
RL <sub>out</sub>	output return loss	G <sub>p</sub> = 14 dB mode	[1]	-	12	-	dB
		bypass mode	[1]	-	10	-	dB
P <sub>L(1dB)</sub>	output power at 1 dB gain compression	G <sub>p</sub> = 14 dB mode; 1 GHz	<u>[1]</u>	-	13	-	dBm
IP3 <sub>0</sub>	output third-order intercept point	G <sub>p</sub> = 14 dB mode	[1][2]	-	29	-	dBm
		bypass mode	[1][2]	-	27	-	dBm

[1] Mode depends on setting of  $V_{CTRL}$ ; see <u>Table 8</u>.

[2] The fundamental frequency (f<sub>1</sub>) is 1000 MHz. The intermodulation product (IM3) is  $2 \times f_2 - f_1$ , where  $f_2 = f_1 \pm 1$  MHz. Input power  $P_i = -10$  dBm.

#### Table 8. Gain selection (pin CTRL)

 $-10 \text{ °C} \leq T_{amb} \leq +70 \text{ °C}$ ; recommended power-up condition:  $V_{CTRL} = \text{logic } 0 \text{ or } < 0.7 \text{ V}$ .

V <sub>CTRL</sub> (V)	Mode
≤ 0.7	bypass
≥ 1.5	$G_p = 14 \text{ dB}$

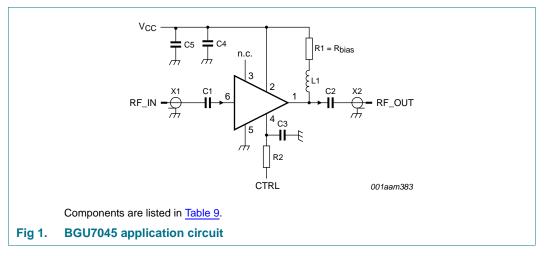
**Remark:**  $V_{CTRL}$  must not exceed  $V_{CC}$ ;  $I_{CTRL}$  must be limited to a maximum of 5 mA.

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## 8. Application information

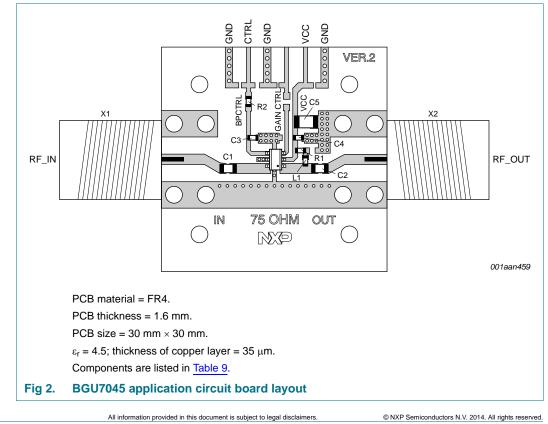
Other applications are possible. Please contact your local sales representative for more information. Application notes are available on the NXP website.

## 8.1 Application circuit



All control and supply lines must be decoupled properly. The decoupling capacitors must be placed as close to the device as possible.

## 8.2 Application circuit board layout



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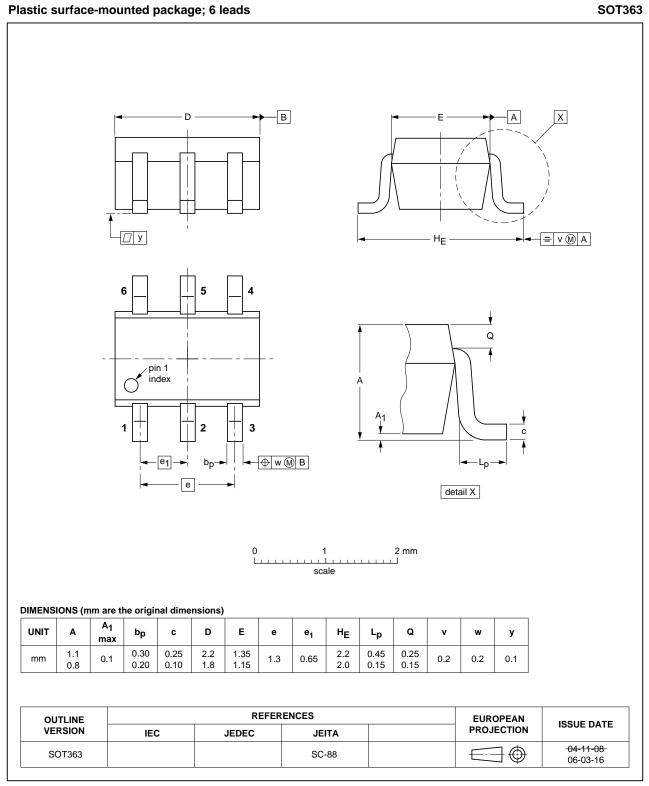
Table 9.	List of components
	1 and Figure 0

See <u>Figure 1</u> and <u>Figure 2</u> .					
Component	Description	Value		Remarks	Function
C1, C2	capacitor	10 nF			DC blocking
C3, C4	capacitor	10 nF			decoupling
C5	capacitor	10 μF			decoupling
L1	chip ferrite bead	1.5 kΩ 🚺	1]	Murata BLM18HE152SN1DF	RF choke
R1	resistor	18 Ω 🚺	1]	R <sub>bias</sub>	bias setting
R2	resistor	1.8 kΩ			current limiting
X1, X2	connector	75 Ω		F-connector, edge mount PCB reflow type, Bomar 861V509ER6	input/output

[1] L1 and R1 must have a power rating of 0.1 W or higher.

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## 9. Package outline



#### Fig 3. Package outline SOT363

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# **10. Abbreviations**

Table 10. Abbreviations		
Acronym	Description	
AC	Alternating Current	
DC	Direct Current	
ESD	ElectroStatic Discharge	
LNA	Low-Noise Amplifier	
MMIC	Monolithic Microwave Integrated Circuit	
PCB	Printed-Circuit Board	
RF	Radio Frequency	
SMD	Surface-Mounted Device	

# **11. Revision history**

### Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BGU7045 v.2	20140526	Product data sheet	-	BGU7045 v.1
Modifications:	• <u>Table 6 on page 3</u> : The information in this table has been updated.			
BGU7045 v.1	20120203	Product data sheet	-	-

# 12. Legal information

### 12.1 Data sheet status

Document status[1][2]	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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